

PRODUCT BULLETIN

PH976DBR 976nm Series

High-Power Single-Frequency Laser Diode

Technology

- DBR Single-Frequency Laser Chip
- InGaAs QW Active Layer
- Epi designed for high reliability

Features

- Available in several package styles
- Pulsed operation for spectral stability at short pulse lengths
- High power for CW applications
- High Slope Efficiency



Description

The PH976DBR Series of high-power edge-emitting lasers are based on Photodigm's advanced singlefrequency laser technology. It provides a diffraction limited, single lateral and longitudinal mode beam. Facets are passivated for high-power reliability. Applications include Yb narrow band pumping, spectroscopy, difference frequency generation, and low power DPSS replacement.

Absolute Maximum Ratings

Parameter	Symbol	Unit	Min	Max
Storage Temperature	T _{STG}	°C	0	80
Operating Temperature	T _{OP}	°C	5.0	70
CW Laser Forward Current, T=T _{op}	I _F	mA	-	250**
Pulsed Laser Forward Current, T=25°C, PW=300 ns, DC=10%	I _F	А	-	0.5
Laser Reverse Voltage	V _R	V	-	2.0
Photodiode Forward Current 1/2/	I _P	mA	-	5.0
Photodiode Reverse Voltage 1/2/	V _R	V	-	20.0
Photodiode Dark Current, V _R =10V, LD I _F =0, <u>2</u> /	I _D	nA	-	50
TEC Current 1/2/	I _{TEC}	А	-2.5	2.5
TEC Voltage 1/ 2/	V _{TEC}	V	-6.0	6.0
Thermistor Current 1/2/	I _{THRM}	mA	-	1.0
Thermistor Voltage 1/2/	V _{THRM}	V	-	10
External Back Reflection	-	dB	-	-14
ESD (HBM)	-	V	-	500
Lead Soldering Temperature, 10 sec. Max., 2/	-	°C	-	260
Fiber Pull Force <u>1</u> /	-	Ν	-	5.0
Fiber Bend Radius <u>1</u> /	-	mm	-	35

1/Butterfly package 2/TO-8 packag** Do not exceed drive current or operating power of supplied LIV**



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CW Characteristics at T_c = 25°C unless otherwise specified

Parameter	Symbol	Unit	Min	Тур	Max				
Center Wavelength	λc	nm	974	976	978				
Optical Output Power @ LIV current	Po	mW	See Power Options Call-out						
Slope Efficiency, <u>1</u> /	ηd	W/A	0.3	0.36					
Slope Efficiency	ηd	W/A	0.6	0.72	-				
Threshold Current	lth	mA	-	30	40				
Laser Series Resistance	Rs	Ω	-	2.0	2.5				
Laser Forward Voltage	V _F	V	-	2.0	2.5				
Thermistor Resistance @ 25°C, 2/	R _T	KΩ	-	10	-				
Photodiode Dark Current, V _R =10V, LD I _F =0, <u>2</u> /	I _D	nA	-	-	50				
Laser Line Width	Δv	MHz	-	8	10				
Beam Divergence @ FWHM	θιι Χ θ⊥	0	-	6 X 32	8 X 34				
Side Mode Suppression Ratio	SMSR	dB	-30	-	-				
Polarization Extinction Ratio, <u>1</u> /	PER	dB	-16	-19	-				
Laser Polarization				TE					
Mode Structure			Fundamental Mode						

1/Butterfly package only 2/Butterfly and TO-8 package

Handling Precautions

These devices are sensitive to ESD. When handling the module, grounded work area and wrist strap must be used. Always store in an antistatic container with all leads shorted together.

How To Order

Part number example: PH976DBR120CM. Assign optical power from those shown below. Use a three-digit format for all power entries. Call factory for special frequency selection and certification to certain atomic absorption lines. Butterfly package is offered at 50% of output power shown.





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